imall

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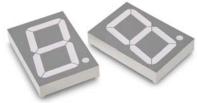
HDSP-H2x1/H2x3

2.3" Single Digit PCB Based LED Display

Data Sheet



CHNOLOGIES



Description

The HDSP-H2x1/H2x3 is a 2.3 inch high, single-digit display series. These halogenated devices utilize AllnGaP red, green and deep red chips. This device is halogenated.

All devices are categorized for luminous intensity. The green device is categorized for color. Use of similar device categories yields a uniform display.

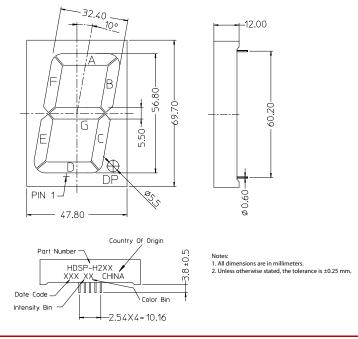
Features

- High reliability
- Excellent characters appearance
- Available in CA and CC
- RoHS Compliant
- Gray top surface with white diffused segments.

Table 1 Ordering Information

Red	Green	Deep Red	Description
HDSP-H2E1	HDSP-H2G1	HDSP-H2A1	Common Anode, Right Hand Decimal
HDSP-H2E3	HDSP-H2G3	HDSP-H2A3	Common Cathode, Right Hand Decimal

Figure 1 Package Dimension



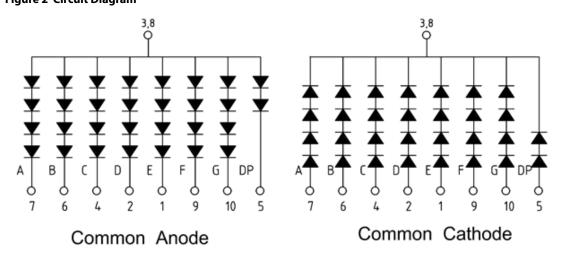


Table 2 Absolute Maximum Ratings at $T_A = 25^{\circ}C$

Parameter	Symbol	Red/Green/Deep Red	Units
Power Dissipation per segment or Dot Point (DP)	P _D	208/104	mW
Continuous Forward Current per segment	۱ _F	20	mA
Peak Forward Current per segment (1/10 Duty Cycle, 0.1m sec pulse width		100	mA
Derating Linearly from 25°C per segment		0.21	mA/°C
Reverse Voltage per segment or DP	V _R	Not designed for reverse biasing	
Operating Temperature	Τ _Ο	-40 to 85	°C
Storage Temperature	Τ _S	-40 to 85	°C
Wave solder Condition 1.6mm below body		260°C peak for 3 secs max	

Table 3 Red Electrical/Optical Characteristics at $T_A = 25^{\circ}C$

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Average Luminous Intensity (Digit Average)	l _v	—	105	—	mcd	I _F = 10 mA
Peak Wavelength	λ _p	—	634	—	nm	I _F = 20 mA
Dominant Wavelength	λ _d	—	625	_	nm	I _F = 20 mA
Forward Voltage per segment / DP	V _F	—	8.0/4.0	10.4/5.2	V	I _F = 20 mA
Reverse Current per segment / DP ^a	I _R	—	—	100	μΑ	V _R = 20V/10V(DP)
Luminous Intensity Matching Ratio (Segment to Segment)	I _{v-M}	—	2:1	—	_	l _F = 10 mA

a. Indicates production go-no-go test only. Long term reverse biasing is not recommended.

Features

Table 4 Green Electrical/Optical Characteristics at $T_A = 25^{\circ}C$

Parameter	Symbol	Min	Тур	Мах	Units	Test Conditions
Average Luminous Intensity (Digit Average)	I _v	—	38	—	mcd	I _F = 10 mA
Peak Wavelength	λ _p	—	570	—	nm	I _F = 20 mA
Dominant Wavelength	λ _d	—	571	—	nm	I _F = 20 mA
Forward Voltage per segment / DP	V _F	—	8.0/4.0	10.4/5.2	V	I _F = 20 mA
Reverse Current per segment / DP ^a	I _R	—	—	100	μΑ	V _R =20V/10V(DP)
Luminous Intensity Matching Ratio (Segment to Segment)	I _{v-M}	_	2:1	_	_	I _F = 10 mA

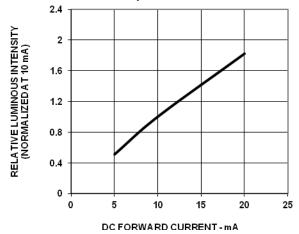
a. Indicates production go-no-go test only. Long term reverse biasing is not recommended.

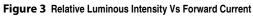
Table 5 Deep Red Electrical/Optical Characteristics at $T_A = 25^{\circ}C$

Parameter	Symbol	Min	Тур	Мах	Units	Test Conditions
Average Luminous Intensity (Digit Average)	l _v	—	95	—	mcd	I _F = 10 mA
Peak Wavelength	λ _p	—	644	—	nm	I _F = 20 mA
Dominant Wavelength	λ _d	—	635	—	nm	I _F = 20 mA
Forward Voltage per segment / DP	V _F	—	8.0/4.0	10.4/5.2	V	I _F = 20 mA
Reverse Current per segment / DP ^a	I _R	—	—	100	μΑ	20V/10V(DP)
Luminous Intensity Matching Ratio	I _{v-M}	_	2:1	—	_	I _F = 10 mA
(Segment to Segment)						

a. Indicates production go-no-go test only. Long term reverse biasing is not recommended.

Red







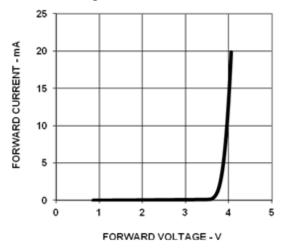


Figure 4 Forward Voltage Vs Current (Segment)

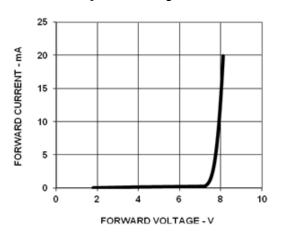
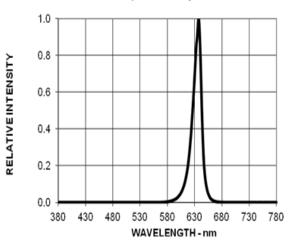


Figure 6 Relative Luminous Intensity Vs Wavelength



Green

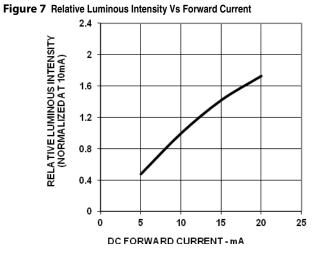
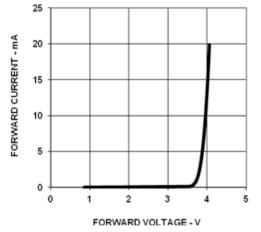


Figure 9 Forward Voltage Vs Current (DP)





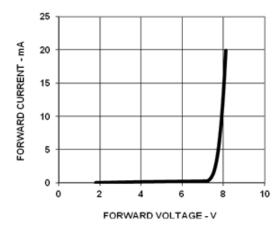
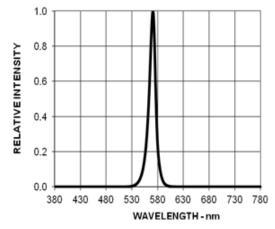
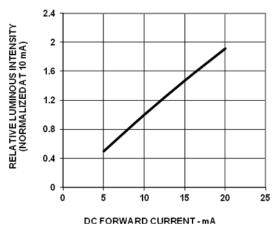


Figure 10 Relative Luminous Intensity Vs Wavelength



Deep Red

Figure 11 Relative Luminous Intensity Vs Forward Current





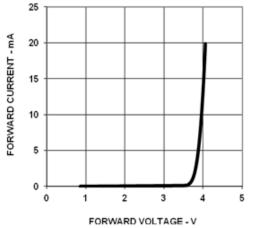
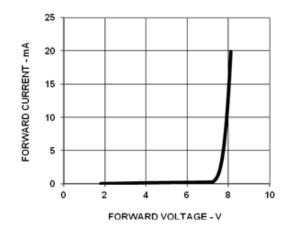
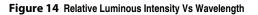
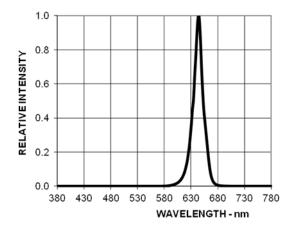


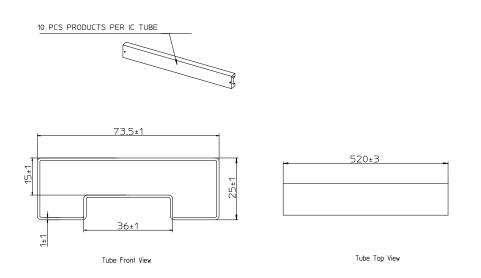
Figure 12 Forward Voltage Vs Current (Segment)







Packing Tube Specifications

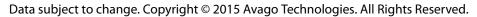


Reference

For further information on soldering LEDs, please refer to Avago Technologies Application Note 1027.

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